RGW60TS65DHR

650V 30A Field Stop Trench IGBT

Datasheet

V _{CES}	650V
I _{C (100°C)}	30A
V _{CE(sat) (Typ.)}	1.5V
P_D	178W

Outline TO-247N (1) (2)(3)

Features

- 1) AEC-Q101 Qualified
- 2) Low Collector Emitter Saturation Voltage
- 3) Low Switching Loss & Soft Switching
- 4) Built in Very Fast & Soft Recovery FRD
- 5) Pb free Lead Plating; RoHS Compliant

Application

Automotive

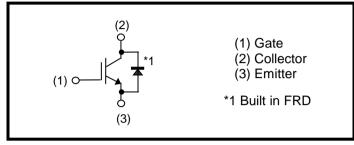
On & Off Board Chargers

DC-DC Converters

PFC

Industrial Inverter

●Inner Circuit



Packaging Specifications

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	Packaging	Tube		
	Reel Size (mm)	-		
Type	Tape Width (mm)	-		
Туре	Basic Ordering Unit (pcs)	450		
	Packing Code	C11		
	Marking	RGW60TS65D		

● Absolute Maximum Ratings (at T_C = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V _{CES}	650	V
Gate - Emitter Voltage		V_{GES}	±30	V
Collector Current	T _C = 25°C	I _C	64	А
Collector Current	T _C = 100°C	I _C	39	А
Pulsed Collector Current	Pulsed Collector Current		120	А
Diode Forward Current	T _C = 25°C	I _F	41	А
	T _C = 100°C	I _F	25	А
Diode Pulsed Forward Current	Diode Pulsed Forward Current		120	А
Power Dissipation	T _C = 25°C	P_{D}	178	W
	T _C = 100°C	P _D	89	W
Operating Junction Temperature		T _j	-40 to +175	°C
Storage Temperature		T _{stg}	-55 to +175	°C

^{*1} Pulse width limited by T_{imax.}

●Thermal Resistance

Parameter	Symbol	Values			Unit
Falametei	Symbol	Min.	Тур.	Max.	Offic
Thermal Resistance IGBT Junction - Case	$R_{\theta(j-c)}$	-	-	0.84	°C/W
Thermal Resistance Diode Junction - Case	$R_{\theta(j-c)}$	-	ı	1.62	°C/W

●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
- Farameter	Symbol		Min.	Тур.	Max.	Offic
Collector - Emitter Breakdown Voltage	BV _{CES}	$I_{C} = 10 \mu A, V_{GE} = 0 V$	650	ı	ı	V
Collector Cut - off Current	I _{CES}	$V_{CE} = 650V, V_{GE} = 0V$	ı	ı	10	μΑ
Gate - Emitter Leakage Current	I _{GES}	$V_{GE} = \pm 30V, V_{CE} = 0V$	1	ı	±200	nA
Gate - Emitter Threshold Voltage	$V_{GE(th)}$	$V_{CE} = 5V, I_{C} = 20.0 \text{mA}$	5.0	6.0	7.0	V
Collector - Emitter Saturation Voltage	V _{CE(sat)}	$I_{C} = 30A, V_{GE} = 15V,$ $T_{j} = 25^{\circ}C$ $T_{j} = 175^{\circ}C$	-	1.5 1.85	1.9 -	V

●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
Parameter			Min.	Тур.	Max.	Offic
Input Capacitance	C _{ies}	$V_{CE} = 30V$,	-	2530	-	
Output Capacitance	C _{oes}	$V_{GE} = 0V$,	-	65	-	pF
Reverse transfer Capacitance	C_{res}	f = 1MHz	-	46	-	
Total Gate Charge	Q_g	V _{CE} = 400V,	-	84	-	_
Gate - Emitter Charge	Q_{ge}	$I_{\rm C} = 30A,$	-	17	-	nC
Gate - Collector Charge	Q_{gc}	$V_{GE} = 15V$	1	31	1	
Turn - on Delay Time	t _{d(on)}		•	36		
Rise Time	t _r	$I_C = 15A, V_{CC} = 400V,$ $V_{GF} = 15V, R_G = 10\Omega,$	ı	9	ı	ns
Turn - off Delay Time	t _{d(off)}	T _j = 25°C Inductive Load *E _{on} include diode reverse recovery	•	107		
Fall Time	t _f		ı	55	ı	
Turn - on Switching Loss	E _{on}		•	0.16	-	mJ
Turn - off Switching Loss	E _{off}		•	0.24		1113
Turn - on Delay Time	t _{d(on)}		ı	34	ı	
Rise Time	t _r	$I_C = 15A, V_{CC} = 400V,$ $V_{GE} = 15V, R_G = 10\Omega,$ $T_i = 175^{\circ}C$	ı	10	ı	ns
Turn - off Delay Time	t _{d(off)}		ı	139	ı	
Fall Time	t _f	Inductive Load	1	76	ı	
Turn - on Switching Loss	E _{on}	*E _{on} include diode reverse recovery	1	0.17	-	mJ
Turn - off Switching Loss	E _{off}	 	1	0.33	ı	1110
Reverse Bias Safe Operating Area	RBSOA	$I_C = 120A, V_{CC} = 520V,$ $V_P = 650V, V_{GE} = 15V,$	FU	LL SQUA	RE	-
Allea		$R_G = 100\Omega, T_j = 175^{\circ}C$				

•FRD Electrical Characteristics (at $T_j = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
	Symbol		Min.	Тур.	Max.	Offic
		I _F = 20A,				
Diode Forward Voltage	V_{F}	T _j = 25°C	-	1.45	1.9	V
		T _j = 175°C	-	1.55	-	
Diode Reverse Recovery Time	t _{rr}	$I_F = 15A,$ $V_{CC} = 400V,$ $di_F/dt = 200A/\mu s,$ $T_j = 25^{\circ}C$	-	87	-	ns
Diode Peak Reverse Recovery Current	I _{rr}		-	5.7	1	А
Diode Reverse Recovery Charge	Q _{rr}		-	0.27	ı	μC
Diode Reverse Recovery Energy	E _{rr}		-	11.0	-	μJ
Diode Reverse Recovery Time	t _{rr}	$I_F = 15A,$ $V_{CC} = 400V,$ $di_F/dt = 200A/\mu s,$ $T_j = 175^{\circ}C$	-	122	-	ns
Diode Peak Reverse Recovery Current	I _{rr}		-	6.9	-	А
Diode Reverse Recovery Charge	Q _{rr}		-	0.51	-	μC
Diode Reverse Recovery Energy	E _{rr}		-	26.5	-	μJ

•Electrical Characteristic Curves

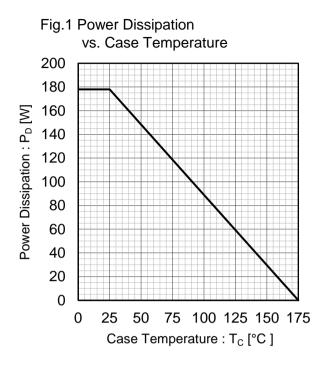
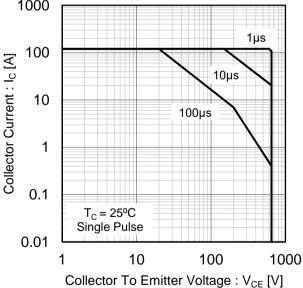


Fig.2 Collector Current vs. Case Temperature 70 60 Collector Current : Ic [A] 50 40 30 20 10 T_j ≤ 175°C V_{GE} ≥ 15V 0 25 50 75 100 125 150 175 Case Temperature : T_C [°C]

Fig.3 Forward Bias Safe Operating Area

1000



160 140 Collector Current : Ic [A] 120 100 80 60 40 20 $T_i \le 175^{\circ}C$ V_{GF} = 15V 0 200 400 600 800 Collector To Emitter Voltage: V_{CE} [V]

Fig.4 Reverse Bias Safe Operating Area

● Electrical Characteristic Curves

Fig.5 Typical Output Characteristics

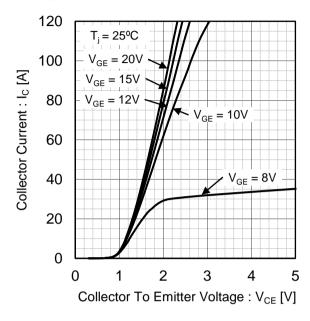


Fig.6 Typical Output Characteristics

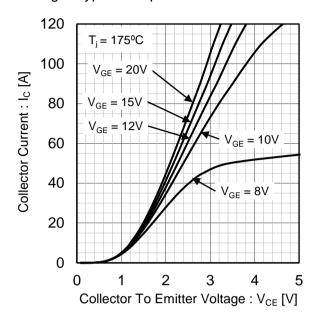


Fig.7 Typical Transfer Characteristics

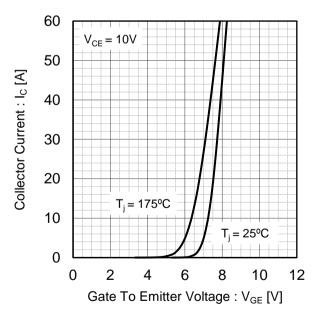
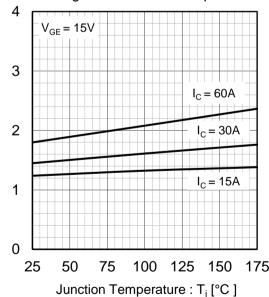


Fig.8 Typical Collector to Emitter Saturation Voltage vs. Junction Temperature



Collector To Emitter Saturation

Voltage: V_{CE(sat)} [V]

Electrical Characteristic Curves

Fig.9 Typical Collector to Emitter Saturation Voltage vs. Gate to Emitter Voltage 20 $T_i = 25^{\circ}C$ Collector To Emitter Saturation $I_C = 60A$ 15 Voltage: V_{CE(sat)} [V] $I_C = 30A$ $I_C = 15A$ 10 5 0 5 10 15 20

Gate To Emitter Voltage: V_{GE} [V]

Fig.10 Typical Collector to Emitter Saturation Voltage vs. Gate to Emitter Voltage

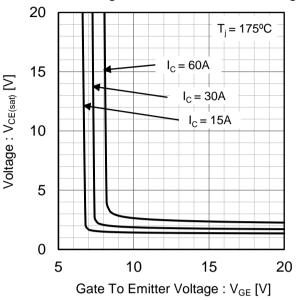
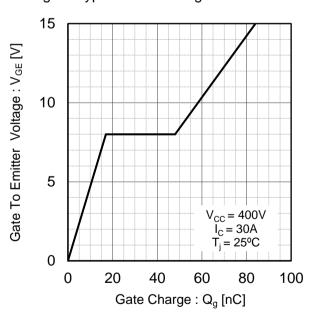


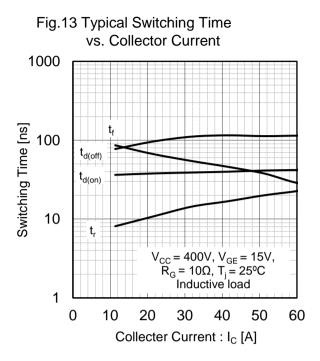
Fig.11 Typical Capacitance vs. Collector to Emitter Voltage 10000 Cies 1000 Capacitance [pF] Coes 100 C_{res} 10 f = 1MHz $V_{GE} = 0V$ = 25°C 0.01 0.1 1 10 100 Collector To Emitter Voltage: V_{CE} [V]

Fig.12 Typical Gate Charge



Collector To Emitter Saturation

• Electrical Characteristic Curves



vs. Gate Resistance $\begin{array}{c} \text{1000} \\ \hline \begin{array}{c} \text{U} \\ \text{U} \\$

Fig.14 Typical Switching Time

Fig.15 Typical Switching Energy Losses vs. Collector Current 10 Switching Energy Losses [mJ] 1 0.1 E_{on} V_{CC} = 400V, V_{GE} = 15V, R_G = 10 Ω , T_j = 25°C Inductive load 0.01 0 10 20 30 40 50 60 Collecter Current : I_C [A]

vs. Gate Resistance

10

See Story

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Eoff

V_{CC} = 400V, V_{GE} = 15V,
I_C = 15A, T_j = 25°C
Inductive load

0 10 20 30 40 50

Gate Resistance : $R_G[\Omega]$

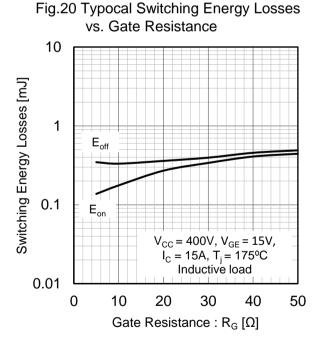
Fig.16 Typocal Switching Energy Losses

• Electrical Characteristic Curves

Fig.17 Typical Switching Time vs. Collector Current 1000 t, Switching Time [ns] 100 $t_{d(off)}$ $t_{d(on)}$ 10 $V_{CC} = 400V, V_{GE} = 15V,$ $R_G = 10\Omega, T_j = 175^{\circ}C$ Inductive load 1 0 10 20 30 40 50 60 Collecter Current : I_C [A]

Fig.18 Typical Switching Time

Fig.19 Typical Switching Energy Losses vs. Collector Current 10 Switching Energy Losses [mJ] 1 $\mathsf{E}_{\mathsf{off}}$ 0.1 E_{on} $V_{CC} = 400V, V_{GE} = 15V,$ $R_G = 10\Omega, T_j = 175^{\circ}C$ Inductive load 0.01 0 10 20 30 40 50 60 Collecter Current : I_C [A]



ROHM

● Electrical Characteristic Curves

Fig.21 Typical Diode Forward Current vs. Forward Voltage

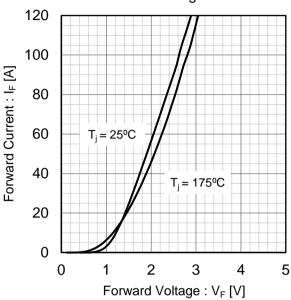


Fig.22 Typical Diode Revese Recovery Time vs. Forward Current

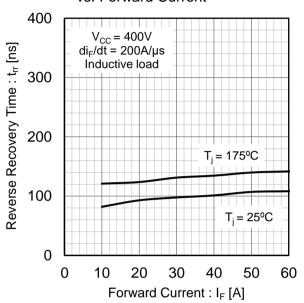


Fig.23 Typical Diode Reverse Recovery Current vs. Forward Current

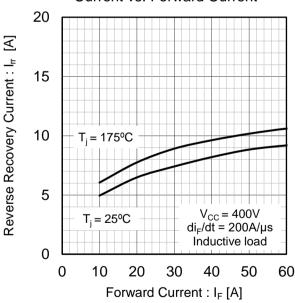
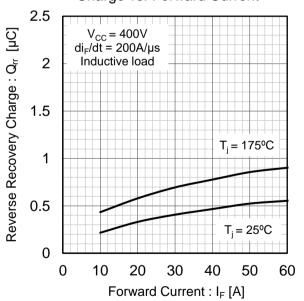


Fig.24 Typical Diode Rrverse Recovery Charge vs. Forward Current



•Electrical Characteristic Curves

Fig.25 Typical IGBT Transient Thermal Impedance

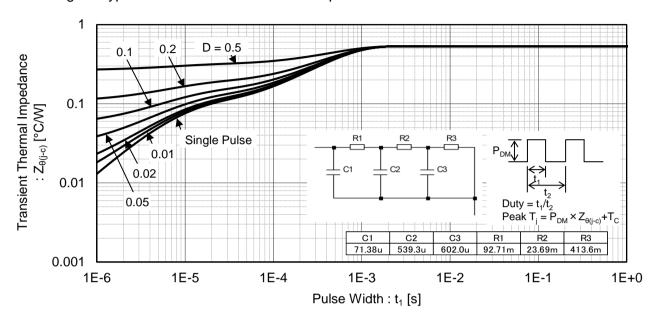
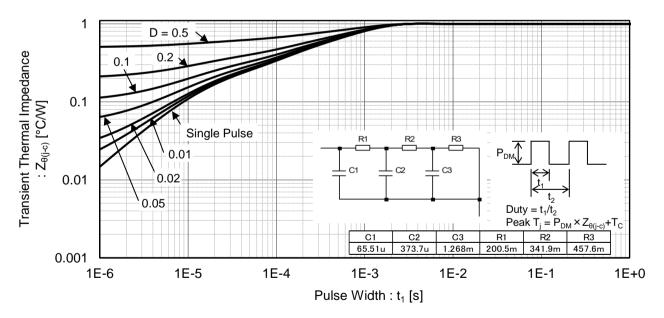


Fig.26 Typical Diode Transient Thermal Impedance



●Inductive Load Switching Circuit and Waveform

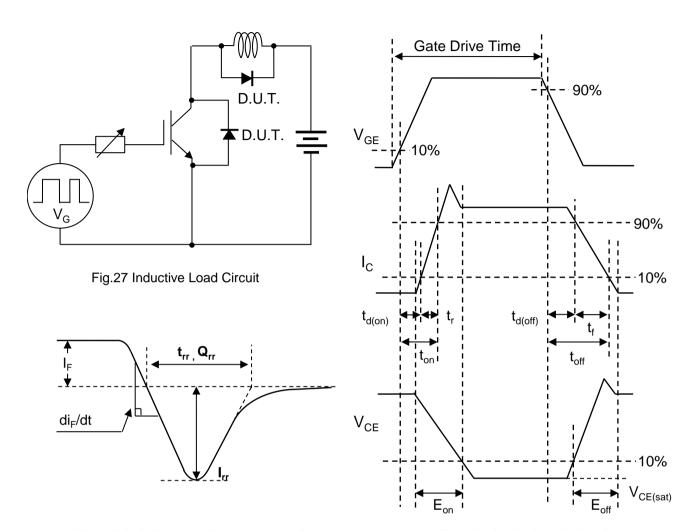


Fig.29 Diode Reverse Recovery Waveform

Fig.28 Inductive Load Waveform

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